9002, 9003, 9004, 9007, 9012, 9016, 9017

NAND Gates/Hex Inverters

The 9002, 9003, 9004, 9007, and 9012 are active LOW level output AND gates commonly known as NAND gates. The 9016 and 9017 are hex inverters with input and output characteristics identical to a NAND gate.

Rochester Electronics Manufactured Components

Rochester branded components are manufactured using either die/wafers purchased from the original suppliers or Rochester wafers recreated from the original IP. All recreations are done with the approval of the OCM.

Parts are tested using original factory test programs or Rochester developed test solutions to guarantee product meets or exceeds the OCM data sheet.

Quality Overview

- ISO-9001
- AS9120 certification
- Qualified Manufacturers List (QML) MIL-PRF-38535
    - Class Q Military
    - Class V Space Level
- Qualified Suppliers List of Distributors (QSLD)
    - Rochester is a critical supplier to DLA and meets all industry and DLA standards.

Rochester Electronics, LLC is committed to supplying products that satisfy customer expectations for quality and are equal to those originally supplied by industry manufacturers.

The original manufacturer's datasheet accompanying this document reflects the performance and specifications of the Rochester manufactured version of this device. Rochester Electronics guarantees the performance of its semiconductor products to the original OEM specifications. 'Typical' values are for reference purposes only. Certain minimum or maximum ratings may be based on product characterization, design, simulation, or sample testing.

9002 • 9003 • 9004
9007 • 9012
9016 • 9017

NAND GATES/HEX INVERTERS

DESCRIPTION — The 9002, 9003, 9004, 9007, and 9012 are active LOW level output AND gates commonly know as NAND gates. The 9016 and 9017 are hex inverters with input and output characteristics identical to a NAND gate.

ORDERING CODE: See Section 9

PKGS	PIN OUT	COMMERCIAL GRADE V_{CC} = +5.0 V ±5%, T_A = 0°C to +75°C	MILITARY GRADE V_{CC} = +5.0 V ±10%, T_A = -55°C to +125°C	PKG TYPE
Ceramic DIP (D)	A	9002DC, 9012DC	9002DM, 9012DM	6A
	B	9003DC	9003DM	
	C	9004DC	9004DM	
	D	9007DC	9007DM	
	E	9016DC, 9017DC	9016DM, 9017DM	
Flatpak (F)	A	9002FC, 9012FC	9002FM, 9012FM	3I
	B	9003FC	9003FM	
	C	9004FC	9004FM	
	D	9007FC	9007FM	
	E	9016FC, 9017FC	9016FM, 9017FM	

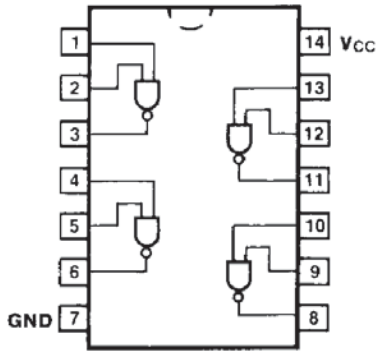
INPUT LOADING/FAN-OUT: See Section 3 for U.L. definitions

PINS	9XXX (U.L.) HIGH/LOW
Inputs	1.5/1.0
Outputs	30*/8.8

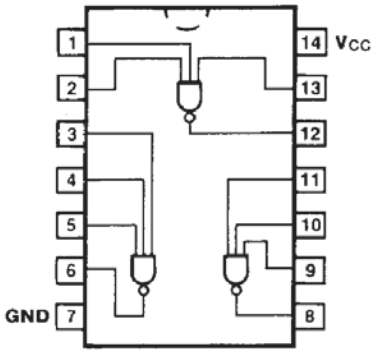
*9012 and 9017 have open-collector outputs

CONNECTION DIAGRAMS

PINOUT A



PINOUT B



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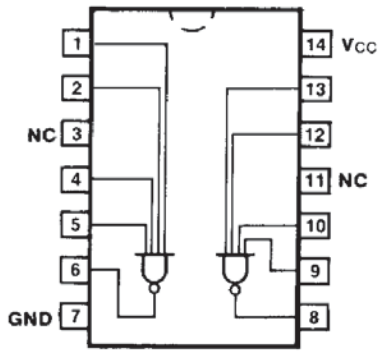
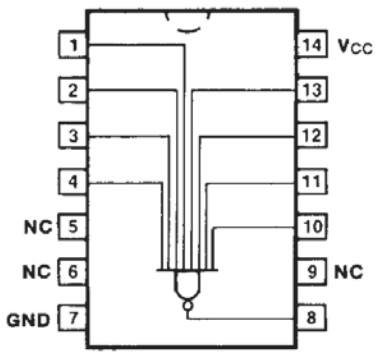
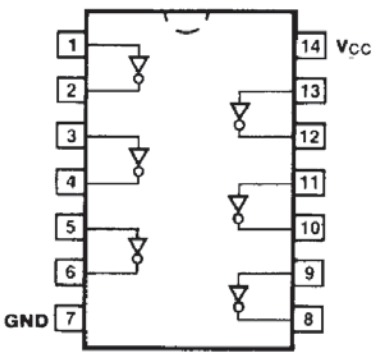


PINOUT D



PINOUT E



DC AND AC CHARACTERISTICS OVER COMMERCIAL TEMPERATURE RANGE: V_{CC} = +5.0 V ±5%

SYMBOL	PARAMETER		0°C Min	0°C Max	25°C Min	25°C Max	75°C Min	75°C Max	UNITS	CONDITIONS
V_{IH}	Input HIGH Voltage		1.9		1.8		1.6		V	Guaranteed Input HIGH Threshold
V_{IL}	Input LOW Voltage			0.85		0.85		0.85	V	Guaranteed Input LOW Threshold
V_{OH}	Output HIGH Voltage (except 9012, 9017)		2.4		2.4		2.4		V	V_{CC} = 4.75 V, I_{OH} = -1.2 mA, Inputs at V_{IL}
V_{OL}	Output LOW Voltage			0.45		0.45		0.45	V	V_{CC} = 5.25 V, I_{OL} = 16 mA, V_{IN} = 5.25 V
				0.45		0.45		0.45		V_{CC} = 4.75 V, I_{OL} = 14.1 mA, Inputs at V_{IH}
I_{IH}	Input HIGH Current					60		60	µA	V_{CC} = 5.25 V, V_{IN} = 4.5 V Gnd on Other Inputs
I_{IL}	Input LOW Current			-1.6		-1.6		-1.6	mA	V_{CC} = 5.25 V V_{IN} = 0.45 V, 5.25 V on Other Inputs
				-1.41		-1.41		-1.41		V_{CC} = 4.75 V V_{IN} = 0.45 V, 5.25 V on Other Inputs
I_{OH}	Output HIGH Current 9012, 9017					250		250	µA	V_{CC} = 4.75 V, V_{IN} = V_{IL}, V_{OUT} = 5.5 V
I_{CC}	Power Supply Current, each gate	ON.		6.1		6.1		6.1	mA	V_{IN} = Open
		OFF		1.7		1.7		1.7		V_{IN} = Gnd
t_{PLH}	Propagation Delay Input to Output				3.0	13			ns	C_L = 15 pF, Fig. 3-4
		9012, 9017			3.0	45				R_L = 4.0 kΩ C_L = 15 pF, Fig. 3-4
t_{PHL}	Propagation Delay Input to Output				3.0	15			ns	C_L = 15 pF, Fig. 3-4
		9012, 9017			3.0	15				R_L = 400 Ω C_L = 15 pF, Fig. 3-4

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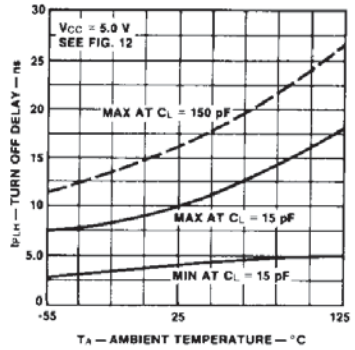
DC AND AC CHARACTERISITICS OVER MILITARY TEMPERATURE RANGE: V_{CC} = +5.0 V ±10%

SYMBOL	PARAMETER		-55°C Min	-55°C Max	25°C Min	25°C Max	125°C Min	125°C Max	UNITS	CONDITIONS
V_{IH}	Input HIGH Voltage		2.0		1.7		1.4		V	Guaranteed Input HIGH Threshold
V_{IL}	Input LOW Voltage			0.8		0.9		0.8	V	Guaranteed Input LOW Threshold
V_{OH}	Output HIGH Voltage (except 9012, 9017)		2.4		2.4		2.4		V	V_{CC} = 4.5 V, I_{OH} = -1.32 mA, Inputs at V_{IL}
V_{OL}	Output LOW Voltage			0.4		0.4		0.4	V	V_{CC} = 5.5 V, I_{OL} = 17.6 mA, V_{IN} = 5.5 V
				0.4		0.4		0.4		V_{CC} = 4.5 V, I_{OL} = 13.6 mA, Inputs at V_{IH}
I_{IH}	Input HIGH Current					60		60	µA	V_{CC} = 5.5 V, V_{IN} = 4.5 V Gnd on Other Inputs
I_{IL}	Input LOW Current			-1.6		-1.6		-1.6	mA	V_{CC} = 5.5 V V_{IN} = 0.4 V 5.5 V on Other Inputs
				-1.24		-1.24		-1.24		V_{CC} = 4.5 V V_{IN} = 0.4 V 5.5 V on Other Inputs
I_{OH}	Output HIGH Current 9012, 9017					250		250	µA	V_{CC} = 4.5, V_{IN} = V_{IL} V_{OUT} = 5.5 V
I_{CC}	Power Supply Current, each gate	ON		5.5		5.5		5.5	mA	V_{IN} = Open
		OFF		1.6		1.6		1.6		V_{IN} = Gnd
t_{PLH}	Propagation Delay Input to Output				3.0	10			ns	C_L = 15 pF, Fig. 3-4
		9012, 9017			3.0	45				R_L = 4.0 kΩ C_L = 15 pF, Fig. 3-4
t_{PHL}	Propagation Delay Input to Output				3.0	12			ns	C_L = 15 pF, Fig. 3-4
		9012,9017			3.0	15				R_L = 400 Ω C_L = 15 pF, Fig. 3-4

WORST CASE TURN OFF DELAY VERSUS AMBIENT TEMPERATURE



WORST CASE TURN ON DELAY VERSUS AMBIENT TEMPERATURE